



3.3V Low Skew 1-to-4 LVTTL/LVCMOS to LVDS Fanout Buffer

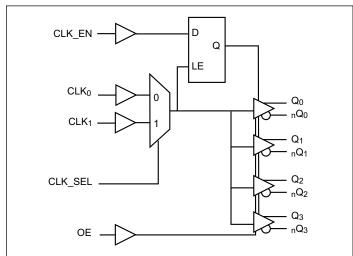
Features

- → Maximum operation frequency: 650 MHz
- → 4 pair of differential LVDS outputs
- → Selectable CLK₀ and CLK₁ inputs
- → CLK₀, CLK₁ accept LVCMOS, LVTTL input level
- → Output Skew: 40ps (maximum)
- → Part-to-part skew: 300ps (maximum)
- → Propagation delay: 2.2ns (maximum)
- → 3.3V power supply
- → Pin-to-pin compatible to ICS8545
- → Operating Temperature: -40°C to 85°C
- → Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- → Halogen and Antimony Free. "Green" Device (Note 3)
- → For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.
 - https://www.diodes.com/quality/product-definitions/
- → Packaging (Pb-free & Green):
 - 20-pin TSSOP (L)

Description

The PI6C48545 is a high-performance low-skew LVDS fanout buffer. PI6C48545 features two selectable single-ended clock inputs and translate to four LVDS outputs. The CLK $_0$ and CLK $_1$ inputs accept LVCMOS or LVTTL signals. The outputs are synchronized with input clock during asynchronous assertion/deassertion of CLK_EN pin. PI6C48545 is ideal for single-ended LVTTL/LVCMOS to LVDS translations. Typical clock translation and distribution applications are data-communications and telecommunications.

Block Diagram



Control Input Function Table

	Inputs			Out	puts
OE	CLK_EN	CLK_SEL	Selected Source	Q ₀ :Q ₃	_n Q ₀ : _n Q ₃
1	0	0	CLK ₀	Diasbled: Low	Diasbled: High
1	0	1	CLK ₁	Disabled: Low	Disabled: High
1	1	0	CLK ₀	Enabled	Enabled
1	1	1	CLK ₁	Enabled	Enabled
0	x	X		HiZ	HiZ

Notes:

1. After CLK_EN switches, the clock outputs are disabled or enabled following a rising and falling input clock edge as show below.

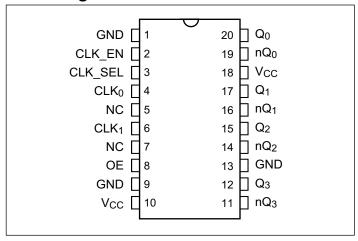
Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.





Pin Configuration



Pin Description

Name	Pin #	Type	Description
GND	1, 9, 13	P	Connect to Ground
CLK_EN	2	I_PU	Synchronizing clock enable. When high, clock outputs follow clock input. When low, Qx outputs are forced low, nQx outputs are forced high. LVCMOS/LVTTL level with $80k\Omega$ pull up.
CLK_SEL	3	I_PD	Clock select input. When high, selects CLK_1 input. When low, selects CLK_0 input. LVCMOS/LVTTL level with $80k\Omega$ pull down.
CLK ₀	4	I_PD	LVCMOS / LVTTL clock input
CLK ₁	6	I_PD	LVCMOS / LVTTL clock input
NC	5, 7		No internal connection.
OE	8	I_PU	Output Enable. Controls outputs Q ₀ , _n Q ₀ through Q ₃ , nQ ₃ .
V _{CC}	10, 18	P	Connect to 3.3V.
Q ₃ , _n Q ₃	12, 11	О	Differential output pair, LVDS interface level.
Q ₂ , _n Q ₂	15, 14	О	Differential output pair, LVDS interface level.
Q ₁ , _n Q ₁	17, 16	О	Differential output pair, LVDS interface level.
Q ₀ , _n Q ₀	20, 19	О	Differential output pair, LVDS interface level.

Notes:

Pin Characteristics

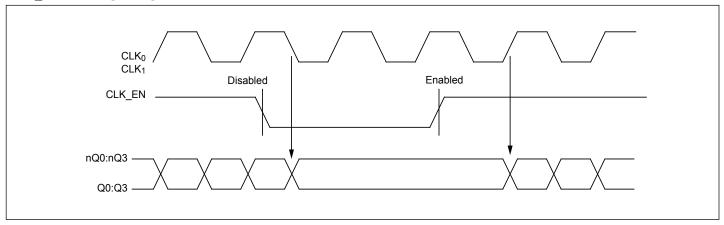
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
C_{IN}	Input Capacitance			6		pF
R_pullup	Input Pullup Resistance			80		l _r O
R_pulldown	Input Pulldown Resistance			80		kΩ

^{1.} I = Input, O = Output, P = Power supply connection, I_PD = Input with pull down, I_PU = Input with pull up.





CLK_EN Timing Diagram



Clock Input Function Table

Inputs	Outputs			
CLK ₀ or CLK ₁	Q ₀ :Q ₃	nQ ₀ :nQ ₃		
0	LOW	HIGH		
1	HIGH	LOW		





Maximum Ratings (Above which the useful life may be impaired. For user guidelines, not tested)

Storage temperature	55 to +150°C
Supply Voltage to Ground Potential (VDD,	$V_{\rm DDO}$) -0.5 to +4.6V
Inputs (Referenced to GND)	0.5 to V _{DD} +0.5V
Clock Output (Referenced to GND)	0.5 to V _{DD} +0.5V
Latch up	200mA
ESD Protection (Input)	2000V min (HBM)
Junction Temperature	150°C max

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Operating Conditions

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
V _{CC}	Power Supply Voltage		3.135	3.3	3.465	V
$T_{\mathbf{A}}$	Ambient Temperature		-40		85	°C
I _{CC}	Power Supply Current				60	mA

LVCMOS/LVTTL DC Characteristics ($T_A = -40^{\circ}$ C to 85° C, $V_{CC} = 3.135$ V to 3.465V unless otherwise stated below.)

Symbol		Parameter	Conditions	Min.	Тур.	Max.	Units
V_{IH}	Input High Voltage	CLK ₀ , CLK ₁ , CLK_EN, CLK_SE, OE		2		V _{CC} +0.3	V
V	, Input Low	CLK ₀ , CLK ₁		-0.3		1.3	V
V _{IL} Voltage	Voltage	CLK_EN, CLK_SEL, OE		-0.3		0.8	V
т	Input High	CLK0, CLK1, CLK_SEL	$V_{IN} = V_{CC} = 3.465V$			150	uA
I_{IH}	Current	CLK_EN, OE	$V_{IN} = V_{CC} = 3.465V$			5	uA
т	Input Low	CLK ₀ , CLK ₁ , CLK_SEL	$V_{IN} = 0V, V_{CC} = 3.465V$	-5			uA
$I_{ m IL}$	Current	CLK_EN, OE	$V_{IN} = 0V, V_{CC} = 3.465V$	-150			uA

LVDS DC Characteristics ($T_A = -40^{\circ}$ C to 85°C, $V_{CC} = 3.135$ V to 3.465V unless otherwise stated below.)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
V _{OD}	Differential Output Voltage		200	280	360	mV
ΔV_{OD}	V _{OD} Magnitude Change			0	40	111 V
Vos	Offset Voltage		1.125	1.3	1.475	V
ΔV_{OS}	V _{OS} Magnitude Change			5	25	mV
I_{OZ}	High Impedance Leakage Current		-10		+10	
I _{OFF}	Power OFF Leakage		-20	±1	+20	μΑ
I _{OSD}	Differential Output Short Circuit Current			-3.5	-5	A
Ios	Output Short Circuit Current			-3.5	-5	mA mA
V _{OH}	Output Voltage High			1.34	1.6	V
V_{OL}	Output Voltage Low		0.9	1.06		v

4





AC Characteristics ($T_A = -40^{\circ}\text{C}$ to 85°C , $V_{CC} = 3.135\text{V}$ to 3.465V)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
f _{max}	Output Frequency				650	MHz
t _{Pd}	Propagation Delay ⁽¹⁾		0.8		2.2	ns
T _{sk(o)}	Output-to-output Skew ⁽²⁾				40	
T _{sk(pp)}	Part-to-part Skew ⁽³⁾				300	ps
t _r /t _f	Output Rise/Fall time	20% - 80%	100		300	
odc	Output duty cycle		48		52	%

Notes:

- 1. Measured from the $V_{CC}/2$ of the input to the differential output crossing point
- 2. Defined as skew between outputs at the same supply voltage and with equal load condition. Measured at the outputs differential crossing point.
- 3. Defined as skew between outputs on different parts operating at the same supply voltage and with equal load condition. Measured at the outputs differential crossing point.
- 4. All parameters are measured at 500MHz unless noted otherwise

Part Marking

PI6C 48545LE CYYWWXX

C: Die Rev YY: Year

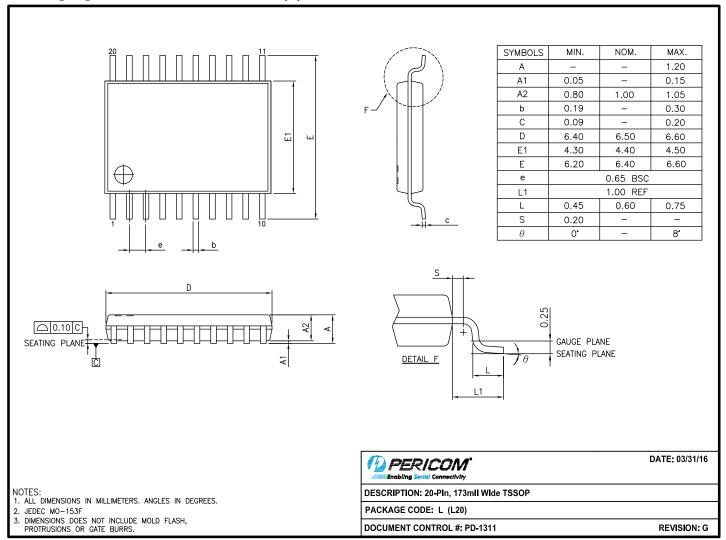
WW: Workweek

1st X: Assembly Code 2nd X: Fab Code





Packaging Mechanical: 20-TSSOP (L)



16-0074

For latest package info.

please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

Ordering Information

Ordering Code	Package Code	Package Description
PI6C48545LEX	L	20-pin, 173-mil Wide (TSSOP)

Notes:

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- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. E = Pb-free and Green
- 5. X suffix = Tape/Reel





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